OPTICAL & PHOTONIC MATERIALSPRODUCTS

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MICROWAVE ACTIVATION OF SOL-GEL SPIN COATED MAGNESIUM DOPED GALLIUM NITRIDE THIN FILMS

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Abstract. In this paper, microwave (MW) activation of sol-gel spin coated magnesium (Mg) doped gallium nitride (GaN) thin films grown on sapphire (001) substrates were reported. The attention was paid to the effects of MW activation power on structural and optical properties of these p-type GaN films. X-ray diffraction results indicate that the Mg-doped GaN thin films exhibit hexagonal wurtzite structure with (002) preferential orientation. Besides, the Mg-doped GaN thin film activated at 450 W has the highest dislocation density, δ , implies that it has the largest amount of nitrogen vacancies compared to all the other samples, and consequently the poorest crystalline quality as proved by the drastic decrease in intensities of the XRD peaks of the film. Since nitrogen vacancies are favourably formed only upon the removal of hydrogen from p-type GaN, it can be deduced that the activation process of Mg dopants is most efficient at 450 W. Tensile strain along caxis of the film activated at 450 W further validates this statement. Raman scattering measurements showed the presence of E₂(high) mode of hexagonal GaN in all the Mg-doped GaN thin films, except in film activated at MW power of 450 W where the E2(high) mode peak is extremely weak and broad. The smallest crystallite size of the Mg-doped GaN thin film activated at MW power of 450 W leads to optical phonon confinement, resulting in broadening of E2(high) mode. In summary, 450 W is the best power for the activation process of Mg dopant, but yet it is not the most ideal MW power because it deteriorates the crystalline quality of the films.

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STRUCTURAL AND OPTICAL PROPERTIES OF AND REDUCED GRAPHENE OXIDE

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Abstract. Natural intercalation of the gran obtained as a product of Hummer's method sonication of water dispersed graphite could be carried out to obtain graphene oxide (GC) and the reduced graphene oxide (RGO).Here we record of metallic nitrate on the oxidation process graphite and then formation of metallic small composites with GO and RGO for the first and observe a change in the efficiency of the second process as we replace the conventionally carries nitrate with that of nickel nitrate NiNC nitrate Cd(NO₃)₂ and zinc nitrate Zn(NO₃). The manual properties were investigated by X-ray official observed the successful formation of composition GO and MO-RGO (M = Zn, Cd, Ni). We strate the the effect on the oxidation process through the second characterization via UV-Vis spectroscopy and Transform Infrared (FTIR) spectroscopy Thermo Gravimetric Analysis (TGA) analysis was out to confirm>90% weight loss in each process proving the reliability of the oxidation cycles. found that the nature of the oxidation more graphite powder and its optical and electronic characteristics can be tuned by replacing the second nitrate (NaNO₃) by other metallic nitrates as the Ni(NO₃)₂ and Zn(NO₃)₂.On the basis of obtained more the synthesized GO and RGO may be experiment promising material in antibacterial activity electrodes fabrication for energy devices such as cell, Fuel cell and super capacitors.

Keywords: Thermal properties of graphene oxide, optical properties of properties fuel cell, composite materials

Keywords: Microwave activation, sol-gel, gallium nitride, spin coating, Mg-dopant.

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